



PTO/SB/08A (10-01)

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Substitute for form 1449A/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(use as many sheets as necessary)</i>				Complete if Known	
				Application Number	09/988,984
				Filing Date	November 19, 2001
				First Named Inventor	John T. Moore
				Art Unit	2812 2823
				Examiner Name	Not Yet Assigned T. PHAM
Sheet	1	of	4	Attorney Docket Number	M4065.0608/P608

U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number-Kind Code ² (if known)			
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PTO/SB/08A (10-01)

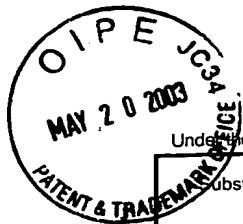
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				Art Unit	2842-2823
				Examiner Name	Not Yet Assigned J. PHAM
Sheet	2	of	4	Attorney Docket Number	M4065.0608/P608

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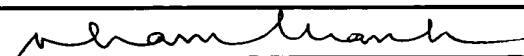
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				Art Unit	2812-2823
				Examiner Name	Not Yet Assigned T. P-HAM
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		Country Code ³ -Number ⁴ -Kind Code ⁵ (if known)				
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	BB					

Examiner Signature		Date Considered	7/21/03
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*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant

¹ Applicant's unique citation designation number (optional). ² See attached Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the application number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. ⁶ Applicant is to place a check mark here if English language Translation is attached.



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Sheet	4	of	4	Attorney Docket Number	M4065.0608/P608

OTHER PRIOR ART – NON PATENT LITERATURE DOCUMENTS			
Examiner Initials ¹	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
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	CP		
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